HALOGEN FREE



Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.41 \text{ V}$ at $I_F = 5 \text{ A}$

TMBS® ITO-220AB



VF60120C

PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 30 A				
V_{RRM}	120 V				
I _{FSM}	300 A				
V _F at I _F = 30 A	0.71 V				
T _J max.	150 °C				
Package	ITO-220AB				
Diode variation Dual Common Cathoo					

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- · Low thermal resistance
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER Maximum repetitive peak reverse voltage		SYMBOL	VF60120C	UNIT	
		V _{RRM}	120	V	
Maximum average forward rectified current (fig. 1)	per device		60	^	
	per diode	I _{F(AV)}	30	A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	300	А	
Isolation voltage from termal to heatsink t = 1 min		V _{AC}	1500	V	
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150	°C	



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	– V _F ⁽¹⁾	0.48	-	V
	I _F = 15 A			0.66	-	
	I _F = 30 A			0.88	0.95	
	I _F = 5 A	T _A = 125 °C		0.41	-	
	I _F = 15 A			0.58	-	
	I _F = 30 A			0.71	0.75	
Reverse current at rated V _R per diode	V _R = 90 V	T _A = 25 °C	I _R ⁽²⁾	14	-	μΑ
		T _A = 125 °C		11	-	mA
	$V_R = 120 V -$	T _A = 25 °C		40	500	μA
		T _A = 125 °C		15	45	mA

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle $^{(2)}\,$ Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	VF60120C	UNIT
Tunical thermal registance	per diode	- R _{θJC}	5.0	- °C/W
Typical thermal resistance	per device		3.8	

ORDERING INFORMATION (Example)						
PACKAGE PREFERRED P/N UNIT WEIGHT (PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
ITO-220AB	VF60120C-M3/4W	1.76	4W	50/tube	Tube	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

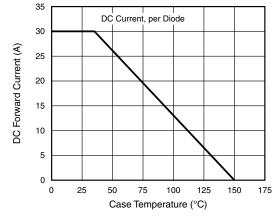


Fig. 1 - Maximum Forward Current Derating Curve

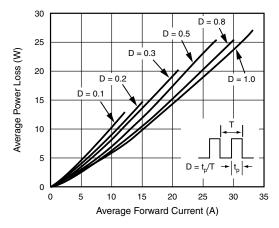


Fig. 2 - Forward Power Loss Characteristics Per Diode



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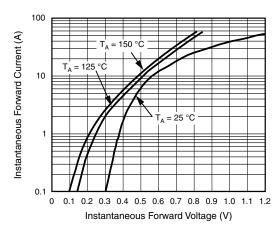


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

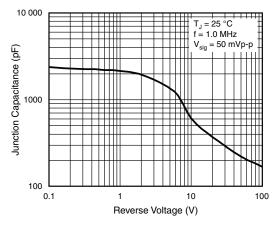


Fig. 5 - Typical Junction Capacitance Per Diode

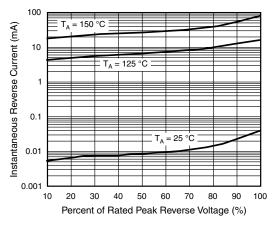
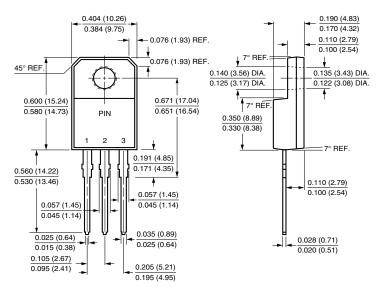


Fig. 4 - Typical Reverse Characteristics Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

ITO-220AB





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